CGY1047

1 GHz, 27 dB gain GaAs push-pull amplifier Rev. 01 — 30 July 2009

Product data sheet

Product profile

1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V Direct Current (DC), employing Heterojunction Field Effect Transistor (HFET) GaAs dies.

1.2 Features

- Excellent linearity, stability and reliability
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Superior levels of ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of the use of certain Hazardous Substances (RoHS)
- Integrated ring wave surge protection

1.3 Applications

CATV systems operating in the 40 MHz to 1003 MHz frequency range

1.4 Quick reference data

Table 1. Quick reference data

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \,^{\circ}\text{C}$; unless otherwise specified.

-1							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gp	power gain	f = 45 MHz		25.0	-	27.0	dB
		f = 1003 MHz		27.0	27.75	28.5	dB
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	<u>[1]</u>	-	-64	-	dBc
CCN	carrier-to-composite noise	$V_0 = 44 \text{ dBmV}$	<u>[1]</u>	-	65	-	dBc
I _{tot}	total current		[2]	230	250	270	mA

^{[1] 79} NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat out level.



^[2] Direct Current (DC).

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2. Pinning information

Table 2. Pinning

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Pin	Description	Simplified outline Graphic symbol
1	input	
2, 3	common	1 3 5 7 9
5	+V _B	
7, 8	common	12 3 7 8
9	output	sym095

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
CGY1047	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{B}	supply voltage			-	30	V
$V_{i(RF)}$	RF input voltage	single tone		-	75	dBmV
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); According JEDEC standard 22-A114E	[1]	-	2000	V
		Biased; According IEC61000-4-2		-	2000	V
T _{stg}	storage temperature			-40	+100	°C
T _{mb}	mounting base temperature			-20	+100	°C

^[1] The value of 2000 V corresponds to a class 2 classification.

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5. Characteristics

Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \degree C$; unless otherwise specified.

	. – ,			•			
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
G_p	power gain	f = 45 MHz		25.0	-	27.0	dB
		f = 1003 MHz		27.0	27.75	28.5	dB
SL _{sl}	slope straight line	f = 45 MHz to 1003 MHz	<u>[1]</u>	1.5	2.0	2.5	dB
FL	flatness of frequency response	f = 45 MHz to 1003 MHz	[2]	-	-	0.8	dB
RLin	input return loss	f = 45 MHz to 200 MHz		20.0	-	-	dB
		f = 200 MHz to 550 MHz		20.0	-	-	dB
		f = 550 MHz to 870 MHz		20.0	-	-	dB
		f = 870 MHz to 914 MHz		20.0	-	-	dB
		f = 914 MHz to 1003 MHz		16.0	-	-	dB
RLout	output return loss	f = 45 MHz to 200 MHz		18.0	-	-	dB
		f = 200 MHz to 550 MHz		18.0	-	-	dB
		f = 550 MHz to 870 MHz		18.0	-	-	dB
		f = 870 MHz to 914 MHz		18.0	-	-	dB
		f = 914 MHz to 1003 MHz		16.0	-	-	dB
NF	noise figure	f = 50 MHz to 870 MHz		-	-	4.0	dB
		f = 870 MHz to 1003 MHz		-	-	4.5	dB
I _{tot}	total current		[3]	230	250	270	mΑ
79 NTSC	channels + 75 digital channels						
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	<u>[4]</u>	-	-64	-	dBc
CSO	composite second-order distortion	$V_0 = 44 \text{ dBmV}$	<u>[4]</u>	-	-66	-	dBc
Xmod	cross modulation	$V_0 = 44 \text{ dBmV}$	<u>[4]</u>	-	-60	-	dB
CCN	carrier-to-composite noise	$V_0 = 44 \text{ dBmV}$	[4]	-	65	-	dBc
79 NTSC	channels						
СТВ	composite triple beat	$V_0 = 44 \text{ dBmV}$	[5]	-	-	-62	dBc
CSO	composite second-order distortion	V _o = 44 dBmV	[5]	-	-	-64	dBc
Xmod	cross modulation	V _o = 44 dBmV	[5]	-	-62	-	dB

^[1] G_p at 1003 MHz minus G_p at 45 MHz.

^[2] Flatness is defined as peak deviation to straight line.

^[3] Direct Current (DC).

^{[4] 79} NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat out level.

^{[5] 79} NTSC channels [f = 55.25 MHz to 550 MHz]; flat out level.

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6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

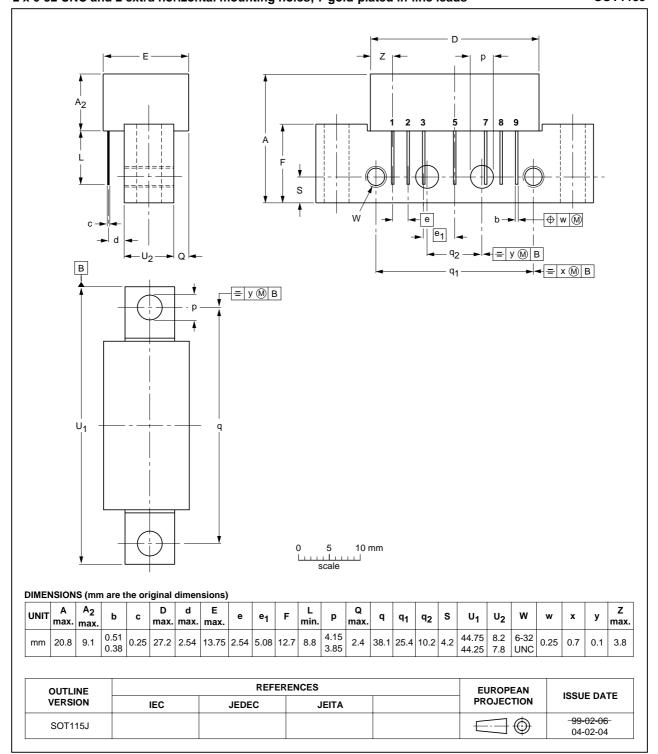


Fig 1. Package outline SOT115J

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7. Abbreviations

Table 6. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
ESD	ElectroStatic Discharge
NTSC	National Television Standard Committee
RF	Radio Frequency
UNC	UNified Coarse

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CGY1047_1	20090730	Product data sheet	-	-

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Legal information

9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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